10UT [ 1IN-[

V<sub>CC</sub>\_/GND∏

1IN+**∏** 

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8 VCC+

6 2IN-

5 2IN+

7

1 20UT

D OR P PACKAGE (TOP VIEW)

2

3

- Wide Gain-Bandwidth Product . . . 4 MHz
- High Slew Rate . . . 13 V/μs
- Fast Settling Time ... 1.1 μs to 0.1%
- Wide-Range Single-Supply Operation . . . 4 V to 36 V
- Wide Input Common-Mode Range Includes Ground (V<sub>CC</sub>\_)
- Low Total Harmonic Distortion . . . 0.02%
- Large-Capacitance Drive Capability . . . 10,000 pF
- Output Short-Circuit Protection

### description

Quality, low-cost, bipolar fabrication with innovative design concepts are employed for the TL3472 operational amplifier. This device offers 4 MHz of gain-bandwidth product, 13-V/ $\mu$ s slew rate, and fast settling time, without the use of JFET device technology. Although the TL3472 can be operated from split supplies, it is particularly suited for single-supply operation because the common-mode input voltage range includes ground potential (V<sub>CC</sub>). With a Darlington transistor input stage, this device exhibits high input resistance, low input offset voltage, and high gain. The all-npn output stage, characterized by no dead-band crossover distortion and large output voltage swing, provides high-capacitance drive capability, excellent phase and gain margins, low open-loop high-frequency output impedance, and symmetrical source/sink ac frequency response. This low-cost amplifier is an alternative to the MC33072 and the MC34072 operational amplifiers.

The TL3472C is characterized for operation from 0°C to 70°C. The TL3472I is characterized for operation from –40°C to 105°C.

AVAILABLE OF HUNS					
	PACKAGED DEVICES				
TA	SMALL OUTLINE (D)	PLASTIC DUAL-IN-LINE (P)			
0°C to 70°C	TL3472CD	TL3472CP			
–40°C to 105°C	TL3472ID	TL3472IP			

#### AVAILABLE OPTIONS

D package is available taped and reeled. Add the suffix R to device type (e.g., TL3472CDR).



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### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)<sup>†</sup>

Supply voltage (see Note 1): V <sub>CC+</sub>	18 V
V <sub>CC</sub> _	
Differential input voltage, VID (see Note 2)	±36 V
Input voltage, V <sub>I</sub> (any input)	
Input current, I <sub>I</sub> (each input)	±1 mA
Output current, I <sub>O</sub>	±80 mA
Total current into V <sub>CC+</sub>	80 mA
Total current out of V <sub>CC</sub>	80 mA
Duration of short-circuit current at (or below) 25°C (see Note 3)	Unlimited
Package thermal impedance, $\theta_{JA}$ (see Notes 4 and 5): D package	97°C/W
P package	85°C/W
Lead temperature 1.6 mm (1/16 inch) from case for 10 seconds	260°C
Storage temperature range, T <sub>stg</sub>	–65°C to 150°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. All voltage values, except differential voltages, are with respect to the midpoint between V<sub>CC+</sub> and V<sub>CC-</sub>.
  - 2. Differential voltages are at the noninverting input with respect to the inverting input. Excessive input current can flow when the input is less than V<sub>CC</sub>- 0.3 V.
  - 3. The output can be shorted to either supply. Temperature and/or supply voltages must be limited to ensure that the maximum dissipation rating is not exceeded.
  - 4. Maximum power dissipation is a function of  $T_J(max)$ ,  $\theta_{JA}$ , and  $T_A$ . The maximum allowable power dissipation at any allowable ambient temperature is  $P_D = (T_J(max) T_A)/\theta_{JA}$ . Operating at the absolute maximum  $T_J$  of 150°C can impact reliability.
  - 5. The package thermal impedance is calculated in accordance with JESD 51.

### recommended operating conditions

		MIN	MAX	UNIT
V <sub>CC±</sub>	Supply voltage	4	36	V
Via	V <sub>CC</sub> = 5 V	0	2.8	V
VIC	Common-mode input voltage $V_{CC\pm} = \pm 15 V$	-15	12.8	
т.	Operating free-air temperature TL3472C	0	70	°C
TA	TL3472I	-40	105	C



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PARAMETER		TEST CONDITIONS		TA	MIN	TYP <sup>†</sup>	MAX	UNIT
			V <sub>CC</sub> = 5 V	25°C		1.5	10	
V <sub>IO</sub>	Input offset voltage			25°C		1.0	10	mV
		V <sub>CC</sub> = ±15 V		Full range‡			12	
$\alpha_{V_{IO}}$	Temperature coefficient of input offset voltage	$V_{IC} = 0,$ $V_{O} = 0,$ $R_{S} = 50 Ω$ $V_{CC} = \pm 15 V$	$V_{CC} = \pm 15 V$	Full range‡		10		μV/∘C
li e	Input offset current		25°C		6	75	<b>P</b> A	
10	input onset current		$V_{CC} = \pm 15 V$	Full range‡			300	nA
Iв	Input bias current	1/22	V <sub>CC</sub> = ±15 V	25°C		100	500	μA
ıΒ	input bias current		$VCC = \pm 12 V$	Full range‡			700	
	Common-mode					-15		
		R <sub>S</sub> = 50 Ω		25°C		to 12.8		v
VICR						-15		
				Full range‡		to		
				0		12.8		
	High-level output voltage	V <sub>CC+</sub> = 5 V,	$V_{CC-} = 0$ , $R_L = 2 k\Omega$	25°C	3.7	4		
Vон		R <sub>L</sub> = 10 kΩ	2. 44	25°C	13.6	14		V
		$R_L = 2 k\Omega$	A 12	Full range‡	13.4			
	Low-level output voltage	V <sub>CC+</sub> = 5 V,	$V_{CC-} = 0$ , $R_L = 2 k\Omega$	25°C		0.1	0.3	
VOL		R <sub>L</sub> = 10 kΩ		25°C		-14.7	-14.3	V
		$R_L = 2 k\Omega$		Full range‡			-13.5	
A. (5)	Large-signal differential voltage amplification	$V_{\Omega} = \pm 10 V$ , $R_{I} = 2 k\Omega$	25°C	25	100		V/m∖	
AVD		$V_{\rm O} = \pm 10 V$ , $K_{\rm L} = 2 K_{\rm M}$		Full range‡	20			V/IIIV
	Short-circuit output current	Source: V <sub>ID</sub> = 1 V,	Source: $V_{ID} = 1 V$ , $V_O = 0$		-10	-34		
los		Sink: $V_{ID} = -1 V$ ,	$V_{O} = 0$	25°C	20	27		mA
CMRR	Common-mode rejection ratio	$V_{IC} = V_{ICR}(min),$	R <sub>S</sub> = 50 Ω	25°C	65	97		dB
ksvr	Supply-voltage rejection ratio $(\Delta V_{CC\pm}/\Delta V_{IO})$	$V_{CC\pm} = \pm 13.5 \text{ V to}$	±16.5 V, $R_{S} = 100 \Omega$	25°C	70	97		dB
	Supply current (per channel)	$V_{O} = 0$ , No load	25°C		3.5	4.5		
ICC		$V_{O} = 0,$ No load		Full range‡		4.5	5.5	mA
		$V_{CC+} = 5 V, V_{O} = 2$	2.5 V, V <sub>CC</sub> _ = 0, No load	25°C		3.5	4.5	

<sup>†</sup> All typical values are at  $T_A = 25^{\circ}C$ . <sup>‡</sup> Full range is 0°C to 70°C for the TL3472C device and -40°C to 105°C for the TL3472I device.



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## operating characteristics, V\_{CC\pm} = $\pm 15$ V, T\_A = 25°C

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
SR+	Positive slew rate	$V_{I} = -10 V$ to 10 V,	A <sub>V</sub> = 1	8	10		V/µs
SR-	Negative slew rate	$R_{L} = 2 k\Omega$ , $C_{L} = 300 pF$	$A_V = -1$		13		V/µs
t <sub>s</sub>	Settling time	A <sub>VD</sub> = −1, 10-V step	To 0.1%		1.1		μs
			To 0.01%		2.2		
Vn	Equivalent input noise voltage	f = 1 kHz,	R <sub>S</sub> = 100 Ω		49		nV/√Hz
In	Equivalent input noise current	f = 1 kHz	= 1 kHz 0.22			pA/√Hz	
THD	Total harmonic distortion	V <sub>O(PP)</sub> = 2 V to 20 V, R <sub>L</sub> =	$p(PP) = 2 V \text{ to } 20 V, R_L = 2 k\Omega, A_{VD} = 10, f = 10 \text{ kHz}$ 0.02				%
GBW	Gain-bandwidth product	f =100 kHz		3	4		MHz
BW	Power bandwidth	$V_{O(PP)} = 20 \text{ V}, \text{ R}_{L} = 2 \text{ k}\Omega,$	A <sub>VD</sub> = 1, THD = 5.0%		160		kHz
	Dhaaa marria	t input noise current       f = 1 kHz       0.22         nonic distortion $V_{O(PP)} = 2 V \text{ to } 20 V$ , $R_L = 2 k\Omega$ , $A_{VD} = 10$ , $f = 10 \text{ kHz}$ 0.02         twidth product       f = 100 kHz       3       4         ndwidth $V_{O(PP)} = 20 V$ , $R_L = 2 k\Omega$ , $A_{VD} = 1$ , THD = 5.0%       160         rgin $R_L = 2 k\Omega$ $C_L = 0$ 70         nin $R_L = 2 k\Omega$ $C_L = 0$ 70         Input resistance $V_{IC} = 0$ 12         Input resistance $V_{IC} = 0$ 150	CL = 0		70		
φm	Phase margin			deg			
	Gain margin		C <sub>L</sub> = 0		12		dB
		K = 2 K S 2	C <sub>L</sub> = 300 pF		4		
r <sub>i</sub>	Differential input resistance	$V_{IC} = 0$	a		150		MΩ
Ci	Input capacitance	$\Lambda$ IC = 0	A A M		2.5		pF
	Channel separation	f = 10 kHz	3 × ×		101		dB
zo	Open-loop output impedance	f = 1 MHz,	A <sub>V</sub> = 1		20		Ω

Ay = 1



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